

10 W Power Amplifier 0.5 - 3 GHz

Rev. V4

Features

Saturated Output Power: 41 dBm

Linear Gain: 24 dB

Power Added Efficiency: 30% at P_{SAT}

50 Ω Input / Output Match

• Ceramic Flange Mount Package

RoHS* Compliant and 260°C Re-flow Compatible

Description

The MAAP-010168 is a two stage MMIC power amplifier designed for broadband high power applications. It can be used as either a driver or an output stage amplifier. This device is fully matched input and output to 50 Ω which eliminates any sensitive external RF tuning components.

The device is packaged in a lead free 10-lead flanged hermetic package for high volume manufacturing.

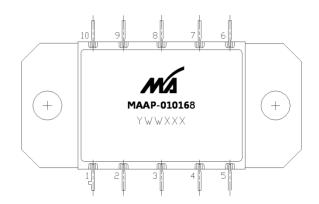
The MAAP-010168 is fabricated using a fully passivated high reliability pHEMT process. The device provides excellent power added efficiency and gain.

Ordering Information¹

Part Number	Package
MAAP-010168-000000	Bulk
MAAP-010168-001SMB	Sample Board

 Reference Application Note M567 for package handling and mounting procedure.

Functional Schematic



Pin Configuration²

Pin #	Function		
1	V _{GG} 2		
2	V _{GG} 1		
3	RF Input ³		
4	V _{GG} 1		
5	V _{GG} 2		
6	V _{DD} 1		
7	V _{DD} 2		
8	RF Output ³		
9	V _{DD} 2		
10	V _{DD} 1		

- 2. Flange is DC and RF ground.
- RF Input & RF Output ports have shunt DC paths to ground. No External DC voltage should be applied to the RF ports.

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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Electrical Specifications:

Freq. = 0.5 - 3.0 GHz, V_{DD} = 10 V, I_{DQ} = 3.5 A, T_A = 25°C, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	Small signal	dB	19	24	_
Input Return Loss	_	dB	_	10	_
Output Return Loss	_	dB	_	10	_
P1dB	_	dBm	_	39	_
P _{SAT}	_	dBm	38	41	_
Current	I _{DQ} P _{SAT}	Α	_	3.5 5.5	_
PAE	P _{SAT}	%	_	30	_
Gate Bias	_	V	_	-0.7	_
Duty Cycle	_	%	_	_	100

Absolute Maximum Ratings^{4,5}

Parameter	Absolute Maximum	
Input Power	24 dBm	
Operating Supply Voltage	+11 V	
Operating Gate Voltage	-2 V	
Operating Temperature	-40°C to +85°C	
Channel Temperature ^{6,7}	+150°C	
Storage Temperature	-65°C to +150°C	

- 4. Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.
- Operating at nominal conditions with T_J ≤ +150°C will ensure MTTF > 1 x 10⁶ hours.
- 7. Junction Temperature (T_J) = T_C + Θ_{JC} * ((V * I) (P_{OUT} P_{IN})) Typical thermal resistance (Θ_{JC}) = 2.0°C/W

a) For $T_C = 25^{\circ}C$ @ 1.5 GHz

 T_J = +80°C @ +10 V, 4 A, P_{OUT} = 41 dBm, P_{IN} = 21 dBm

b) For $T_C = 85^{\circ}C$ @ 1.5 GHz

 T_J = +138°C @ +10 V, 3.9 A, P_{OUT} = 41 dBm, P_{IN} = 21 dBm

Operating the MAAP-010168

The MAAP-010168 is static sensitive. Please handle with care. To operate the device, follow these steps. Ramp down or shutdown in reverse order (gate bias on first and off last). All V_{GG} pins should have the same voltage applied at all times.

- 1. Apply V_{GG} (-1.5 V).
- 2. Apply V_{DD} (10.0 V Typical).
- 3. Set I_{DQ} by adjusting V_{GG} .
- 4. Apply RF_{IN}.

Handling Procedures

Please observe the following precautions to avoid damage:

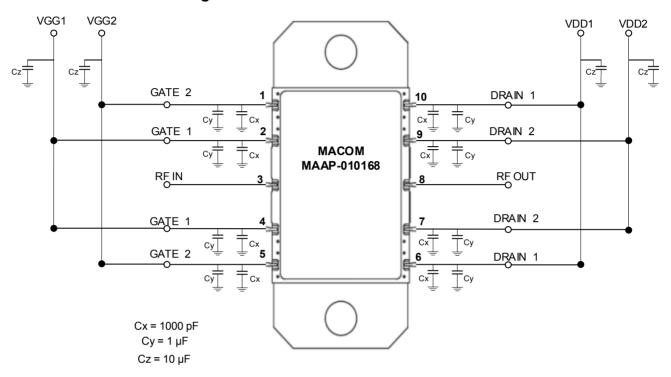
Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

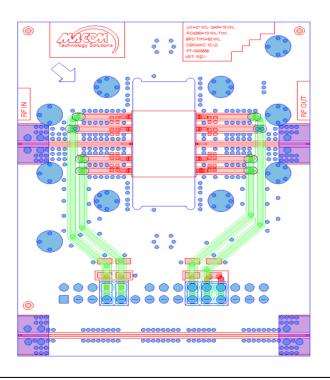


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Recommended Bias Configuration



Sample Board Layout





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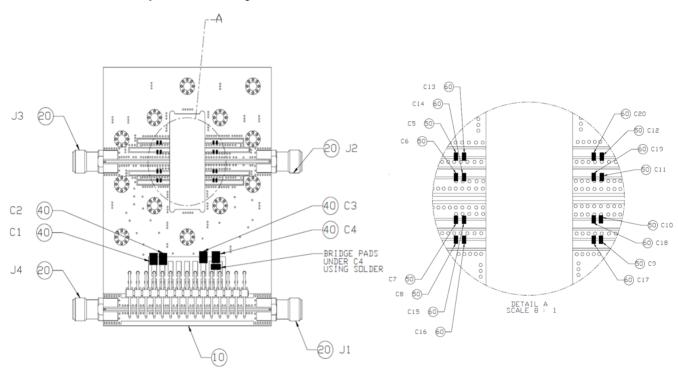
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MAAP-010168 Recommended Layout

Below is the recommended layout for the MAAP-010168. For optimal stability MACOM recommends adding bias decoupling capacitors of 10 μ F at the entry point of V_G and V_{DD} (At the DC connections Header PIN). It is also recommended to add shunt decoupling capacitors of 1 μ F & 1000 pF at the gate and drain pins of MAAP-010168 as shown in the details A below.

MACOM can provide gerber files of the sample board layout upon request.

MAAP-010168 Sample Board Layout



Parts List

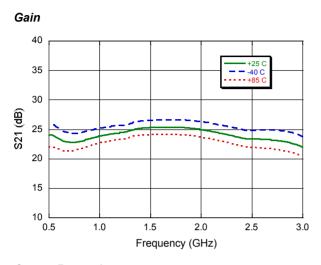
Item #	Component / Description
10	Test Board, RO4350 , ½ Oz copper , 10 mil thick
20	SMA Edge Mount Connectors
30	2x15 Right Angle Connector, 0.1 Grid
40	Capacitor, 10 μF, 10%, 16 V, 1210, X5R
50	Capacitor, 1 µF, 10%, 16 V, 0402, X5R
60	Capacitor, 1000 pF, 10 %, 25 V, 0402, X5R



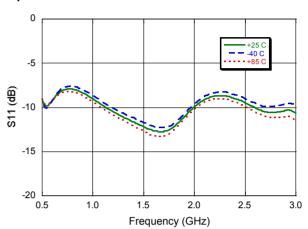
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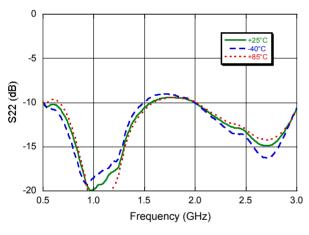
Typical Performance Curves



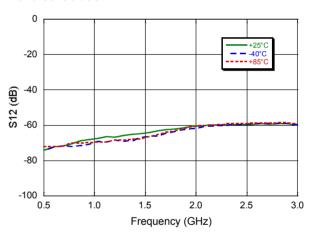
Input Return Loss



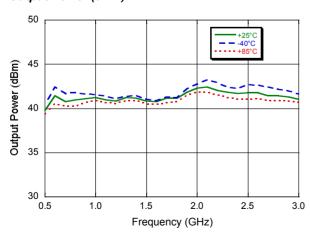
Output Return Loss



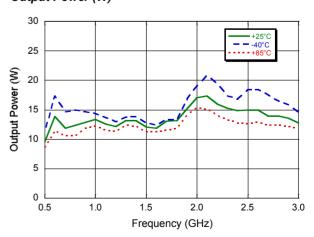
Reverse Isolation



Output Power (dBm)



Output Power (W)



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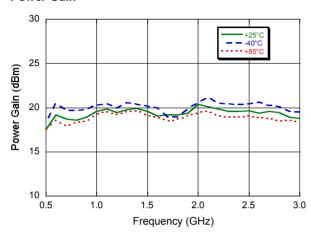
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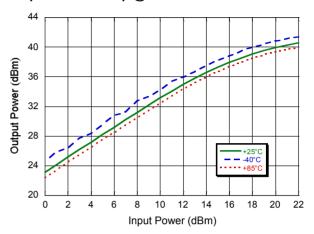
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Typical Performance Curves

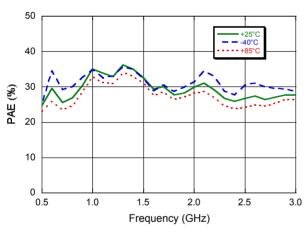
Power Gain



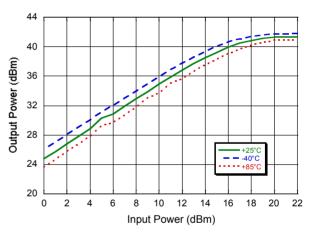
Output Power Sweep @ 0.7 GHz



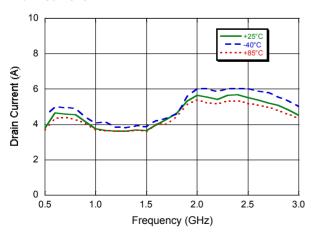
Power Added Efficiency



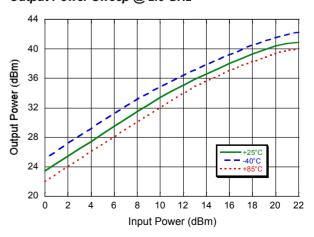
Output Power Sweep @ 1.5 GHz



Drain Current



Output Power Sweep @ 2.5 GHz



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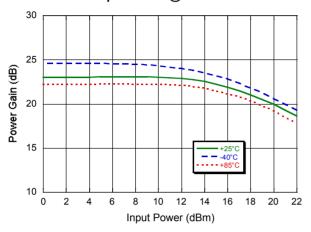
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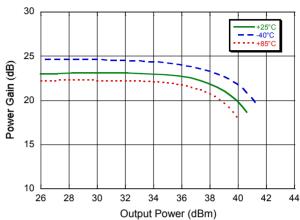
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Typical Performance Curves

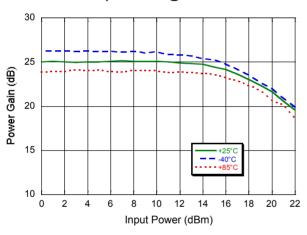
Power Gain vs. Input Power @ 0.7 GHz



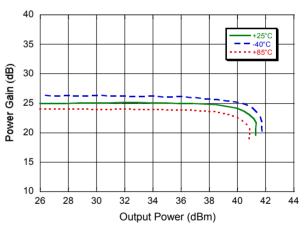
Power Gain vs. Output Power @ 0.7 GHz



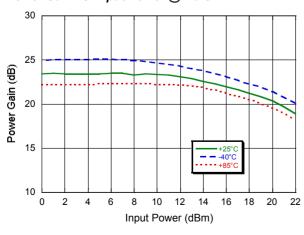
Power Gain vs. Input Power @ 1.5 GHz



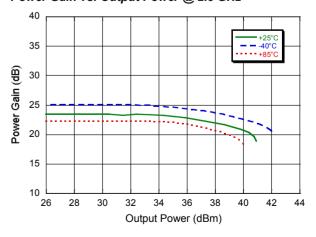
Power Gain vs. Output Power @ 1.5 GHz



Power Gain vs. Input Power @ 2.5 GHz



Power Gain vs. Output Power @ 2.5 GHz



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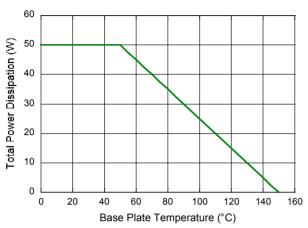
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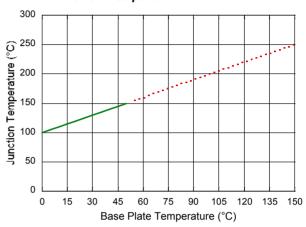
Typical Performance Curves

Max. Power Dissipation vs. Base Plate Temperature⁷

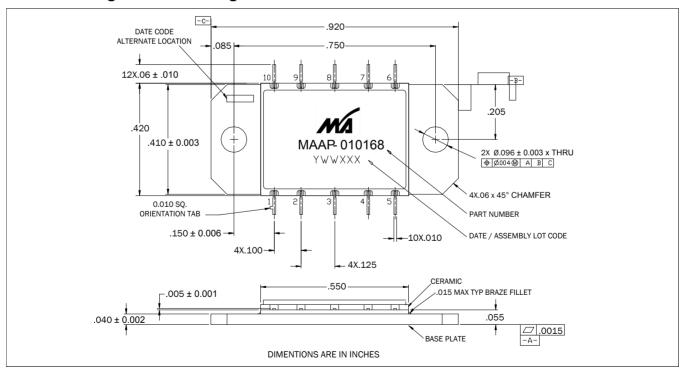


 Power dissipation should not exceed the maximum plot shown above to maintain T_J <150°C. It is recommended to monitor power dissipation and decrease power dissipation in the device as required.

Junction Temperature vs. Base Plate Temperature with 50 W Power Dissipation



Ceramic Flange Mount Package[†]



Reference Application Note M538 for lead-free solder reflow recommendations.
This is a high frequency, low thermal resistance package. The package consists of a cofired ceramic construction with a copper-tungsten base and iron-nickel-cobalt leads. The finish consists of electrolytic gold over nickel plate.

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